

	<h2 style="color: red;">SI3909DV-T1-GE3</h2>	
	Hersteller-Teilenummer:	SI3909DV-T1-GE3
	Hersteller / Marke:	Vishay / Siliconix
	Teil der Beschreibung:	MOSFET 2P-CH 20V 6TSOP
Datenblätter:	 SI3909DV-T1-GE3.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 13030 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen

Teilenummer	SI3909DV-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2P-CH 20V 6TSOP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	13030 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	1.15W
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Typ FET	2 P-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	-
Rds On (Max) @ Id, Vgs	200 mOhm @ 1.8A, 4.5V
VGS (th) (Max) @ Id	500mV @ 250µA (Min)
Gate Charge (Qg) (Max) @ Vgs	4nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)



















































SI3909DV-T1-GE3 ist neu im Original, Suche SI3909DV-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3909DV-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI3909DV-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI3909DV-T1 SIL SI3909DV-T1 SIL</p>	 <p>SI3909DV-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 6TSOP</p>	 <p>SI3911DV-T1 VISHAY SI3911DV-T1 VISHAY</p>	 <p>SI3909DV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 6TSOP</p>
 <p>SI3911DV SI SI3911DV SI</p>	 <p>SI3911DV-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 1.8A 6TSOP</p>	 <p>SI3909DV-T1-E3 Vishay / Siliconix MOSFET 2P-CH 20V 6TSOP</p>	 <p>SI3911DV-T1-E3 Vishay / Siliconix MOSFET 2P-CH 20V 1.8A 6TSOP</p>

heiße Teile

Mehr

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|--|--|---|--|---|
|  SI3865CDV-T1-GE3 |  SI3865CDV-T1-GE3 |  SI3865DV-T1 |  SI3865DV-T1-E3 |  SI3865DV-T1-GE3 |
|  SI3867DV-T1-E3 |  SI3867DV-T1-E3 |  SI3867DV-T1-GE3 |  SI3867DV-T1-GE3 |  SI3879DV-T1-E3 |
|  SI3879DV-T1-E3 |  SI3900DV |  SI3900DV-T1-E3 |  SI3900DV-T1-E3 |  SI3900DV-T1-GE3 |
|  SI3900DV-T1-GE3 |  SI3905DV-T1 |  SI3905DV-T1-E3 |  SI3905DV-T1-E3 |  SI3905DV-T1-GE3 |
|  SI3905DV-T1-GE3 |  SI3909DV-T1 |  SI3909DV-T1-E3 |  SI3909DV-T1-E3 |  SI3909DV-T1-GE3 |
|  SI3911DV |  SI3911DV-T1 |  SI3911DV-T1-E3 |  SI3911DV-T1-E3 |  SI3911DV-T1-G33 |
|  SI3911DV-T1-GE3 |  SI3911DV-T3-E3 |  SI3915DV |  SI3915DV-T1-E3 |  SI3915DV-T1-GE3 |
|  SI3932DV-T1-GE3 |  SI3932DV-T1-GE3 |  SI3948DV-T1 |  SI3948DV-T1-E3 |  SI3948DV-T1-E3 |
|  SI3948DV-T1-GE3 |  SI3948DV-T1-GE3 |  SI3951-KU |  SI3951DV-T1-E3 |  SI3951DV-T1-E3 |
|  SI3951DV-T1-GE3 |  SI3951DV-T1-GE3 |  SI3981DV-T1-E3 |  SI3981DV-T1-E3 |  SI3981DV-T1-GE3 |

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